340KHz, 3A Step-down Converter With Soft-Start

General Description

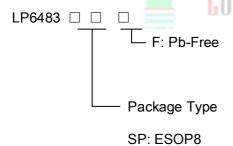
The LP6483 contains an independent 340KHz constant frequency, current mode, PWM step-down converters. The converter integrates a main switch and a synchronous rectifier for high efficiency without an external Schottky diode. The converter can supply 3A of load current. The LP6483 can also run at 98% duty cycle for low dropout applications. It provides fast transient response and cycle-by-cycle limit with current mode control.

The LP6483 is available in a ESOP8 package and is rated over the -40°C to 85°C temperature range.

Features

- Input Voltage Range: 4.5V to 30V
- ◆ Output Voltage Range: 0.6V to 12V
- ◆ 3A Load Current
- ◆ Up to 95% Efficiency
- ◆ 340KHz Switching Frequency
- ◆ Short Circuit Protection
- ◆ Thermal Fault Protection
- ♦ ESOP8 Package
- ◆ RoHS Compliant and 100% Lead (Pb)-Free

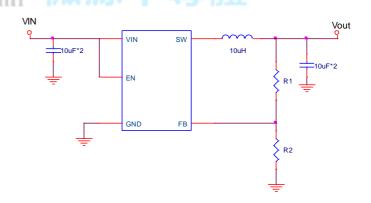
Order Information



Applications

- ♦ Portable Media Players
- ♦ Cellular and Smart mobile phone
- ♦ PDA/DSC
- ♦ GPS Applications

Typical Application Circuit



Marking Information

Device	Marking	Package	Shipping				
LP6483SPF	LPS	SP:ESOP8	4K/REEL				
	LP6483						
YWX							
Y: Year code. W: Week code. X: Batch numbers.							

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Functional Pin Description

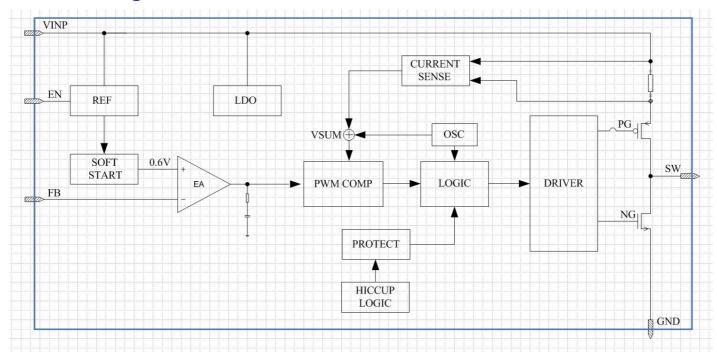
Package Type	Pin Configurations			
ESOP-8	NC 1 VIN 2 SW 3 GND 4	9 GND	8 NC 7 EN 6 NC 5 FB	

Pin Description

Pin	Name	Description
1/6/8	NC	No Connector.
2	VIN	Supply Input.
3	SW	Switch Mode Connection to Inductor. This pin connects to the drains of the internal main
		and synchronous power MOSFET switches.
4/9	GND	Ground. LOW OWER JEHR 1733 1735 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
5 FB		Feedback Input. Connect FB to the center point of the external resistor divider. Normal
5	1.0	voltage for this pin is 0.6V.
7	EN	Enable Control Input. Drive EN above 2.5V to turn on the Channel. Drive EN below 0.4V
		to turn it off (shutdown current < 0.1µA).

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Function Diagram



Absolute Maximum Ratings Note 1

\diamond	VIN/SW/EN to GND	36V
\$	FB to GND (VFB)	0.3V to 6V
	Junction Temperature	150°C
	Storage Temperature	65°C to 165°C
	Operating Ambient Temperature Range (T _A)	40°C to 85°C
	Maximum Soldering Temperature (at leads, 10sec)	260°C

Note 1. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Thermal Information

\diamondsuit	Maximum Power Dissipation (SOP8, P _D ,T _A =25°C)		2W
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Thermal Resistance (SOP8, θ_{JA}) ------ 50°C/W

ESD Susceptibility

\diamond	HBM(Human Body	y Mode)		2K\	/
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MM(Machine Mode) ------ 200V

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Electrical Characteristics

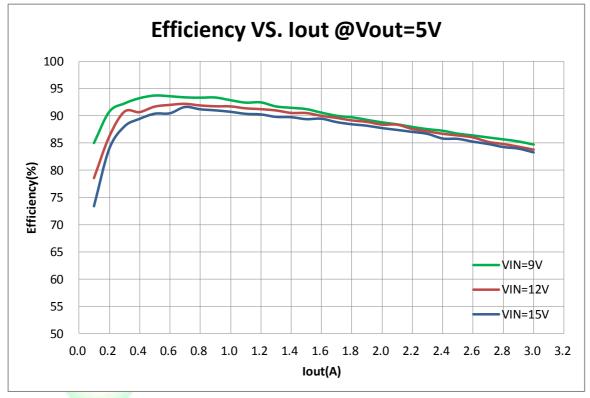
 V_{IN} =12V, V_{EN} =5V, L=10uH, T_A =25°C, unless otherwise noted

Symbol	Parameter	Condition	Min	Тур	Max	Units
VIN	Input Voltage		4.5		30	V
VIN-OVP	VIN OVP Voltage Lockout Threshold			32		
Vouт	Output Voltage Range		0.6		12	V
Ιq	Quiescent Current	V _{IN} =12V		10		mA
I _{SHDN}	Shutdown Current	EN=GND		10		μΑ
ILIM	P-Channel Current Limit			4.5		Α
R _{DS(ON)_} H	High-Side Switch On Resistance			70		mΩ
R _{DS(ON)_L}	Low-Side Switch On Resistance			50		mΩ
ILX_LEAK	LX Leakage Current	V _{EN} =0V, V _{SW} =0 or 5V, V _{IN} =5V		1		μA
V _{FB}	Feedback Threshold Voltage Accuracy	V _{IN} =12V	0.588	0.6	0.612	V
I _{FB}	FB Leakage Current	V _{OUT} =5.0V			30	nA
fosc	Oscillator Frequency			340		KHz
ts	Startup Time	From Enable to Output Regulation		2.7		mS
T _{SD}	Over-Temperature Shutdown Threshold	rsemi 依冰牙干	导'	150		°C
T _{HYS}	Over-Temperature Shutdown Hysteresis			20		°C
V _{EN(L)}	Enable Threshold Low				1	V
V _{EN(H)}	Enable Threshold High		2.5			V
I _{EN}	Enable Current	V _{IN} =12V, V _{EN} =12V		5		μA

Note: Output Voltage: $V_{OUT} = V_{FB} \times (1 + R_1/R_2)$ Volts;

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Typical Operating Characteristics



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Application Information

The LP6483 operates by a constant frequency, current mode architecture. The output voltage is set by an external divider returned to the FB pin. An error amplifier compares the divided output voltage with a reference voltage of 0.6V and adjusts the peak inductor current accordingly.

Thermal Protection

The total power dissipation in LP6483 is limited by a thermal protection circuit. When the device temperature rises to approximately 150°C, this circuit turns off the output, allowing the IC to cool. The thermal protection circuit can protect the device from being damaged by overheating in the event of fault conditions. Continuously running the LP6483 into thermal shutdown degrades device reliability.

Setting Output Voltage

The output voltage is set with a resistor divider from the output node to the FB pin. It is recommended to use divider resistors with 1% tolerance or better. To improve efficiency at very light loads consider using larger value resistors. If the values are too high the regulator is more susceptible to noise and voltage errors from the FB input current are noticeable. For most applications, a resistor in the $10k\Omega$ to $1M\Omega$ range is suggested for R_{UP} and R_{DN}. The output voltage is established by the following equations

$$V_{OUT}=0.6V\times(1+R_1/R_2)$$

Where V_{REF} is 0.6V.

Inductor Selection

The inductor is required to supply constant current to the output load while being driven by the switched input voltage. A larger value inductor results in less ripple current and lower output ripple voltage. However, the larger value inductor has a larger physical size, higher series resistance, and lower saturation current. Choose an inductor that does not saturate under the worst-case load conditions. A good rule for determining the inductance is to allow the peak-to-peak ripple current in the inductor to be approximately 30% of the maximum load current. The inductance value can be calculated by the equation:

$$L=(V_{OUT})\times(V_{IN}-V_{OUT})/(V_{IN}\times f\times\Delta I)$$

Output Capacitor

The output capacitor is required to maintain the DC output voltage. Low ESR capacitors are preferred to keep the output voltage ripple low. characteristics of the output capacitor also affect the stability of the regulator control loop. Ceramic, tantalum, or low ESR electrolytic capacitors are recommended. In the case of ceramic capacitors, the impedance at the switching frequency is dominated by the capacitance. The output voltage ripple is estimated to be:

$$V_{RIPPLE}=1.4\times V_{IN}\times (f_{LC}/f)^2$$

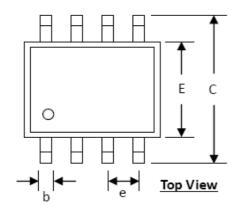
Where V_{RIPPLE} is the output ripple voltage, V_{IN} is the input voltage, f_{LC} is the resonant frequency of the LC filter, f is the switching frequency. In the case of tantalum or low ESR electrolytic capacitors, the ESR dominates the impedance at the switching frequency, and so the output ripple is calculated as:

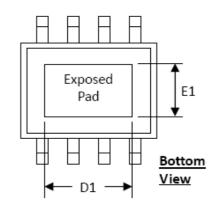
Where V_{RIPPLE} is the output voltage ripple, ΔI is the inductor ripple current, and R_{ESR} is the equivalent series resistance of the output capacitors.

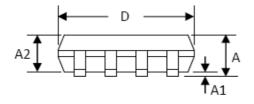


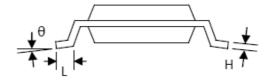
Packaging Information

ESOP8









SYMBOLS	DIMENSION (MM)		DIMENSION (INCH)		
STIVIBOLS	MIN	MAX	MIN	MAX	
А	1.30	1.70	0.051	0.067	
A1	0.00	0.15	0.000	0.006	
A2	1.25	1.52	0.049	0.060	
b	0.33	0.51	0.013	0.020	
С	5.80	6.20	0.228	0.244	
D	4.80	5.00	0.189	0.197	
D1	3.15	3.45	0.124	0.136	
E	3.80	4.00	0.150	0.157	
E1	2.26	2.56	0.089	0.101	
е	1.27 BSC		0.050) BSC	
Н	0.19	0.25	0.0075	0.0098	
L	0.41	1.27	0.016	0.050	
θ	0°	8°	0°	8°	

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